

View Online at <https://aerobasegroup.com/nsn/5961-00-222-7331>

Inclosure Material:

Glass all semiconductor device diode

Overall Length:

0.150 inches all semiconductor device diode and 0.170 inches all semiconductor device diode

Terminal Length:

1.000 inches all semiconductor device diode

Overall Diameter:

0.068 inches all semiconductor device diode and 0.076 inches all semiconductor device diode

Function For Which Designed:

Switching

End Application:

Nimitz class cvn

Internal Configuration:

Junction contact all semiconductor device diode

Internal Junction Configuration:

Pn all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

4 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

10.0 breakdown voltage, dc all semiconductor device diode

Current Rating Per Characteristic:

10.00 microamperes collector current, dc peak all semiconductor device diode

Terminal Type And Quantity:

2 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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